

30V N-Channel Enhancement Mode MOSFET

Description

The SX10N03SI uses advanced trench technology to provide excellent R_{DS(ON)}, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

V_{DS} = 30V I_D =10A

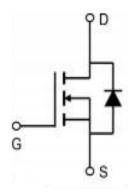
 $R_{DS(ON)} < 20m\Omega$ @ $V_{GS}=10V$

Application

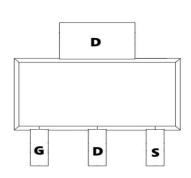
Lithium battery protection

Wireless impact

Mobile phone fast charging







Absolute Maximum Ratings (Tc=25°Cunless otherwise noted)

Symbol	Parameter	Rating	Units
Vos	Drain-Source Voltage	30	V
Vgs	Gate-Source Voltage	Gate-Source Voltage ±20	
l o@Ta=25℃	Continuous Drain Current	Continuous Drain Current 10	
l o@Ta=70°C	Continuous Drain Current	Continuous Drain Current 6.9	
lом	Pulsed Drain Current ²	30	А
PD@TA=25°C	Total Power Dissipation ³	1	W
Тѕтс	Storage Temperature Range	-55 to 150	$^{\circ}$
TJ	Operating Junction Temperature Range	-55 to 150	°C
Reja	Thermal Resistance Junction-ambient ¹	125	°C/W
Reja	Thermal Resistance Junction-Ambient ¹ (t ≤10s)	85	°C/W



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Electrical Characteristics (Tc=25℃ unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit	
BVDSS	Drain-Source Breakdown Voltage	Vgs=0V , Ip=250uA	30	32		V	
△BVDSS/△TJ	BVDSS Temperature Coefficient	Reference to 25℃, I _D =1mA		0.029		V/°C	
RDS(ON)	Static Drain-Source On-Resistance ²	Vgs=10V , Ip=5.8A		17	20		
RDS(ON)	Static Drain-Source On-Resistance ²	Vgs=4.5V , Ip=5A		25	32	mΩ	
VGS(th)	Gate Threshold Voltage	Vgs=Vps , Ip =250uA	1.2	1.6	2.5	V	
△VGS(th)	V _{GS(th)} Temperature Coefficient	VGS-VDS , ID -250UA		-2.82		mV/℃	
IDSS	Drain-Source Leakage Current	V _{DS} =24V , V _{GS} =0V , T _J =25℃			1	uA	
1033		V _{DS} =24V , V _{GS} =0V , T _J =55°C			5		
IGSS	Gate-Source Leakage Current	Vgs=±12V , Vps=0V			±100	nA	
gfs	Forward Transconductance	V _{DS} =5V , I _D =5A		25		S	
Rg	Gate Resistance	V _{DS} =0V , V _{GS} =0V , f=1MHz		1.5		Ω	
Qg	Total Gate Charge (4.5V)			11.5			
Qgs	Gate-Source Charge	VDS=15V , VGS=4.5V , ID=5.8A		1.6		nC	
Qgd	Gate-Drain Charge			2.9			
Td(on)	Turn-On Delay Time			5			
Tr	Rise Time	V _{DD} =15V , V _{GS} =10V , R _G =3Ω		47.			
Td(off)	Turn-Off Delay Time	lo=5A		26		ns	
Tf	Fall Time			8			
Ciss	Input Capacitance			860			
Coss	Output Capacitance	V _{DS} =15V , V _{GS} =0V , f=1MHz		84		рF	
Crss	Reverse Transfer Capacitance			70			
ls	Continuous Source Current ^{1,4}	V _G =V _D =0V , Force Current			5.8	Α	
Vsp	Diode Forward Voltage ²	V _G s=0V , I _S =1A , T _J =25℃			1.2	V	

Note:

- 1. The data tested by surface mounted on a 1 inch 2 FR-4 board with 2OZ copper.
- 2_{\times} The data tested by pulsed , pulse width $\ \leq 300 \text{us}$, duty cycle $\ \leq 2\%$
- 3. The power dissipation is limited by 150℃ junction temperature
- 4. The data is theoretically the same as I_D and I_{DM} , in real applications, should be limited by total power dissipation.

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Typical Characteristics

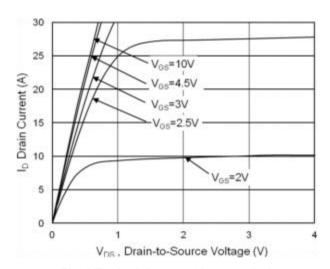


Fig.1 Typical Output Characteristics

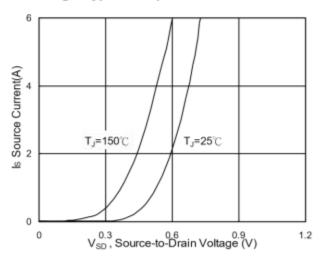


Fig.3 Forward Characteristics Of Reverse

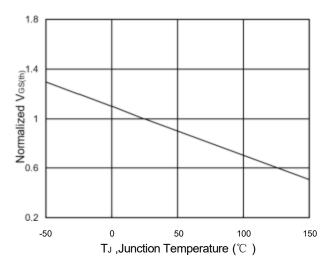


Fig.5 Normalized V_{GS(th)} vs. T_J

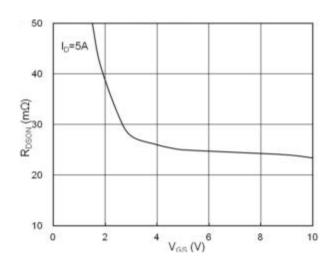


Fig.2 On-Resistance vs. Gate-Source

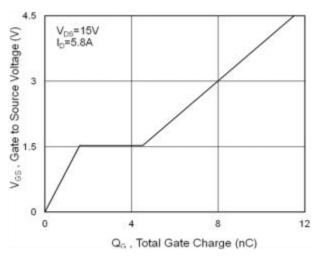


Fig.4 Gate-Charge Characteristics

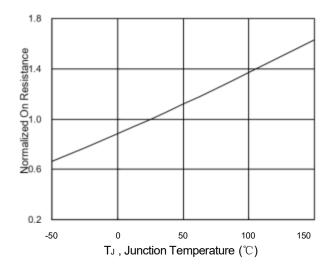
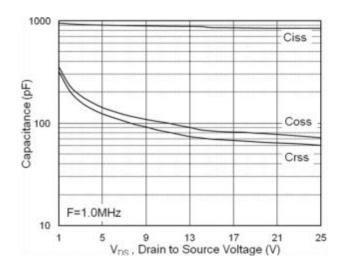


Fig.6 Normalized R_{DSON} vs. T_J



Typical Characteristics



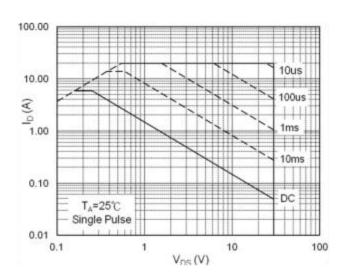


Fig.7 Capacitance

Fig.8 Safe Operating Area

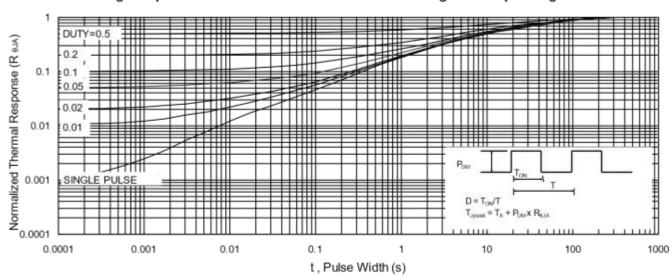


Fig.9 Normalized Maximum Transient Thermal Impedance

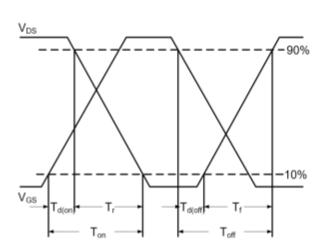


Fig.10 Switching Time Waveform

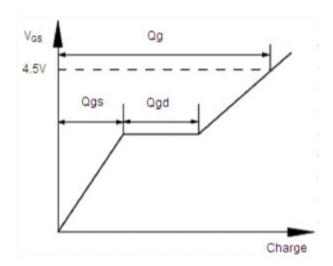
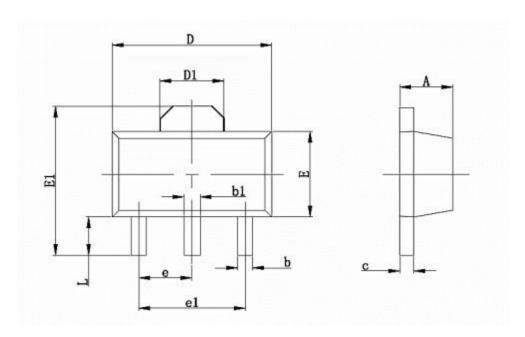


Fig.11 Gate Charge Waveform



Package Mechanical Data:SOT89-3L



Symbol	Dimensions	In Millimeters	Dimension	s In Inches
	Min	Max	Min	Max
Α	1.400	1.600	0.055	0.063
b	0.350	0.520	0.013	0.197
b1	0.400	0.580	0.016	0.023
С	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550 REF		0.061 REF	
E	2.350	2.550	0.091	0.102
E1	3.940	4.250	0.155	0.167
е	1.500 TYP		0.06	OTYP
e1	3.000 TYP		0.118	8TYP
L	0.900	1.100	0.035	0.047

Package Marking and Ordering Information

dokage marking and Ordering information					
Product ID	Pack Marking		Qty(PCS)		
TAPING	SOT89-3L		3000		

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